Power MOSFET

40 V, 2.9 m Ω , 127 A, Dual N-Channel

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- NVMFD5C446NWF Wettable Flank Option for Enhanced Optical Inspection
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter		Symbol	Value	Unit	
Drain-to-Source Voltage		V_{DSS}	40	V	
Gate-to-Source Voltage	Э		V_{GS}	±20	V
Continuous Drain		$T_C = 25^{\circ}C$	I _D	127	Α
Current R _{θJC} (Notes 1, 2, 3)	Steady State	T _C = 100°C		90	
Power Dissipation		T _C = 25°C	P _D	89	W
R _{θJC} (Notes 1, 2)		T _C = 100°C		44	
Continuous Drain	Steady State	T _A = 25°C	I _D	24	Α
Current R _{0JA} (Notes 1, 2, 3)		T _A = 100°C		17	
Power Dissipation		T _A = 25°C	P_{D}	3.2	W
R _{θJA} (Notes 1 & 2)		T _A = 100°C		1.6	
Pulsed Drain Current	$T_A = 25^{\circ}C$, $t_p = 10 \mu s$		I _{DM}	637	Α
Operating Junction and Storage Temperature		T _J , T _{stg}	-55 to + 175	°C	
Source Current (Body Diode)		IS	74	Α	
Single Pulse Drain-to-Source Avalanche Energy ($T_J = 25$ °C, $I_{L(pk)} = 11$ A)		E _{AS}	223	mJ	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		TL	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{ heta JC}$	1.7	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	47	

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- 2. Surface–mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
- 3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

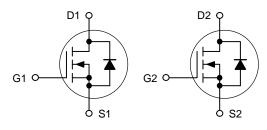


ON Semiconductor®

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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
40 V	$2.9~\text{m}\Omega~@~10~\text{V}$	127 A

Dual N-Channel





MARKING DIAGRAM D1 D1 S1 D1 G1 XXXXXXX D1 S2 AYWZZ D2 G2 D2 D2

XXXXXX = 5C446N (NVMFD5C446N) or 446NWF (NVMFD5C446NWF)

A = Assembly Location

Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

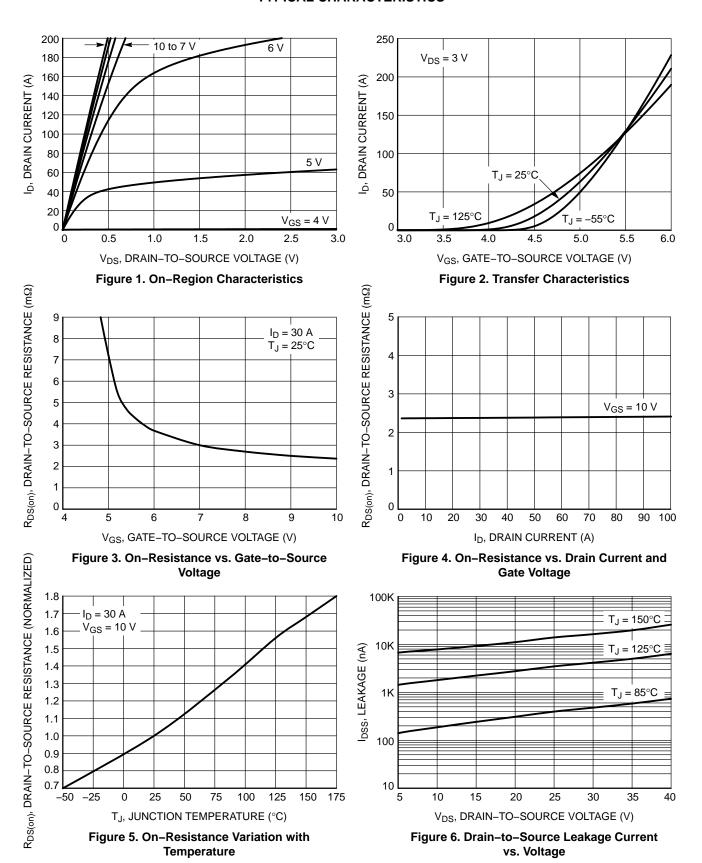
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS					•		•
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /				30		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	I_{DSS} $V_{GS} = 0 \text{ V}, \qquad T_{J} = 25$	T _J = 25 °C			10	
		$V_{DS} = 40 \text{ V}$	T _J = 125°C			100	μΑ
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS}$	= 20 V			100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D =$: 250 μA	2.5		3.5	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-6.4		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A		2.4	2.9	mΩ
CHARGES, CAPACITANCES & GATE RES	STANCE						
Input Capacitance	C _{ISS}				2450		pF
Output Capacitance	C _{OSS}	$V_{GS} = 0 \text{ V, f} = 1 \text{ MHz}$	z, V _{DS} = 25 V		1200		
Reverse Transfer Capacitance	C _{RSS}	-			44		1
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 10 \text{ V}, V_{DS} = 32 \text{ V}; I_D = 30 \text{ A}$			38		nC
Threshold Gate Charge	Q _{G(TH)}				7.0		
Gate-to-Source Charge	Q_{GS}				11		
Gate-to-Drain Charge	Q_{GD}				7.0		
Plateau Voltage	V_{GP}				4.5		V
SWITCHING CHARACTERISTICS (Note 5)							
Turn-On Delay Time	t _{d(ON)}				18		
Rise Time	t _r	$V_{GS} = 10 \text{ V}, V_{DS} = 32 \text{ V},$ $I_{D} = 30 \text{ A}, R_{G} = 1.0 \Omega$			39		- ns
Turn-Off Delay Time	t _{d(OFF)}				47		
Fall Time	t _f				17		
DRAIN-SOURCE DIODE CHARACTERISTI	CS						
Forward Diode Voltage V _S	V_{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		0.8	1.2	_ v
		$I_{S} = 30 \text{ A}$	T _J = 125°C		0.7		
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V, dIS/dt} = 100 \text{ A/}\mu\text{s,}$ $I_{S} = 30 \text{ A}$			50		
Charge Time	t _a				25		ns
Discharge Time	t _b				25		1
Reverse Recovery Charge	Q _{RR}				35		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$.

5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

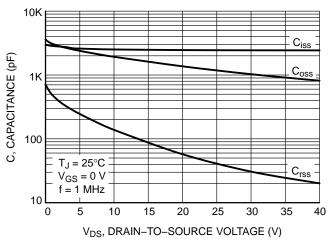


Figure 7. Capacitance Variation

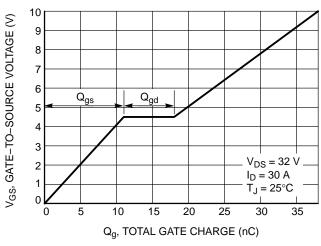


Figure 8. Gate-to-Source vs. Total Charge

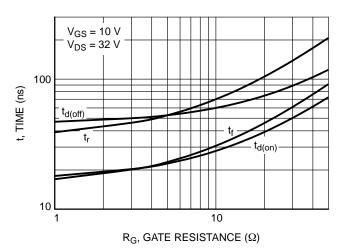


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

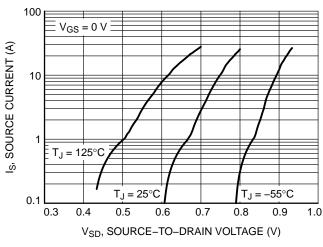


Figure 10. Diode Forward Voltage vs. Current

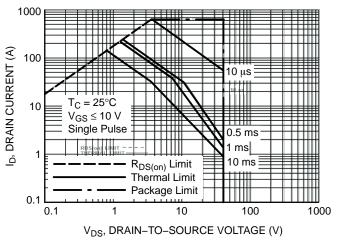


Figure 11. Maximum Rated Forward Biased Safe Operating Area

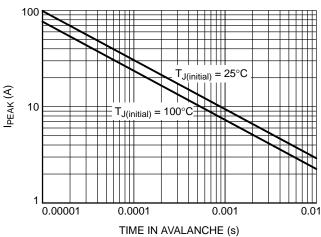


Figure 12. Maximum Drain Current vs. Time in Avalanche

TYPICAL CHARACTERISTICS

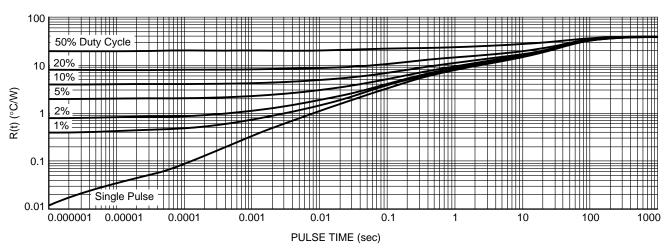


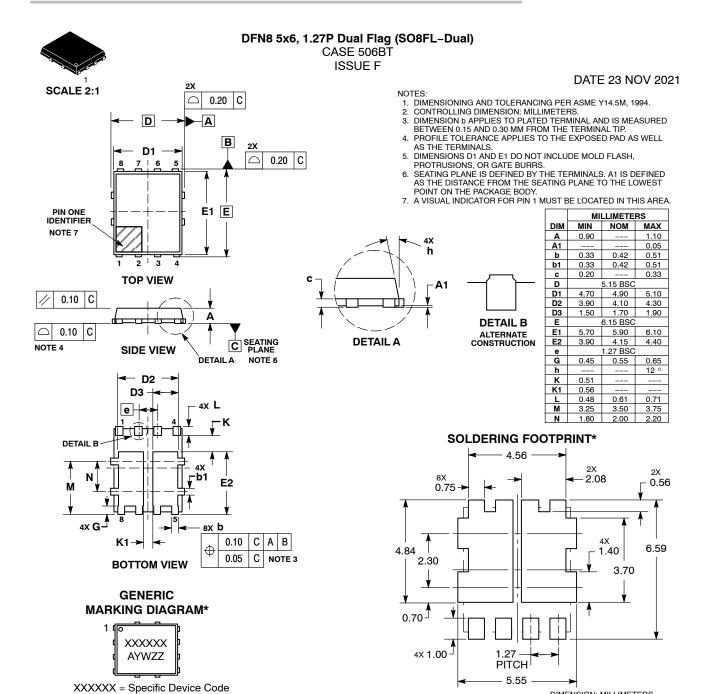
Figure 13. Thermal Response

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMFD5C446NT1G	5C446N	DFN8 (Pb-Free)	1500 / Tape & Reel
NVMFD5C446NWFT1G	446NWF	DFN8 (Pb–Free, Wettable Flanks)	1500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*	This information is generic. Please refer to
	device data sheet for actual part marking.
	Pb-Free indicator, "G" or microdot "■", may
	or may not be present. Some products may
	not follow the Generic Marking.

= Work Week

= Lot Traceability

= Year

Υ

W

77

DOCUMENT NUMBER:

= Assembly Location

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DESCRIPTION: DFN8 5X6, 1.27P DUAL FLAG (SO8FL-DUAL)

98AON50417E

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